Photo-Electrochemical Studies on TiO$_2$-Doped Ce (III/IV) Oxides Nanoparticles in Aqueous Electrolytes

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**ABSTRACT**

Photoelectrochemical studies on TiO$_2$ doped with Ce$_2$O$_3$ or CeO$_2$ took place in aqueous solutions of [Fe(CN)$_6$]$_{4-}$ as the source of hydrated electrons. Our studies show that doping TiO$_2$ with CeO$_2$ gave better photocatalytic reduction of [Fe(CN)$_6$]$_{3-}$ than TiO$_2$ doped with Ce$_2$O$_3$. However the TiO$_2$ assemblies doped with either Ce(III) or Ce(IV) oxides give less photochemical reduction of [Fe(CN)$_6$]$_{3-}$ than the oxides of pure metals (Ti or Ce). In both cases a lowering of the band gaps of TiO$_2$ was noticed. Immobilized TiO$_2$ doped with Ce oxides on a FTO (Fluorine Ten Oxide) surface gave greater photocurrent with I$_2$/I$_3$ than that recorded for [Fe(CN)$_6$]$_{3-}$/4$^-$ redox systems. Our studies indicate that the TiO$_2$ doped with Ce$_2$O$_3$ or CeO$_2$ maintained photoactivity after being immobilized in thin solid sheets and can be used in all solid state photoelectron-chemical cells.

**Keywords:** Photoelectrochemical; Doped TiO$_2$; Ceric Oxide; Nanoparticles; Photocatalysis

1. Introduction

Doping transition metal ions into the oxides of other transition metals has been widely performed on semiconductors to minimize or eliminate electron/hole recombination and enhance their absorption towards the visible light region [1-4]. To name but few that TiO$_2$ doping with Fe(III), Mo(V), Ru(III), Os(III), Re(V), V(IV/V) and Zn(II) has been reported [5,6]. These studies were extended to use some rare earth ions as dopants in some stable photoactive transition metal oxides such as TiO$_2$ [7-9]. Photo-dissociation of water into hydrogen and oxygen using powder suspensions of some semiconductors was recently reported by several researchers [10-17]. Most of the studies of the photo-dissociation of water were done over compact semiconductor electrodes [11]. Because of their larger surface areas [17] and their ability to carry out all reactions that were previously associated with massive semiconductor electrodes, colloidal semiconductors were used. In some systems, platinized semiconductors powders such as TiO$_2$ were used for simultaneous production of oxygen and hydrogen. Several methods were used to generate ordered assemblies of narrow band gap semiconductor nanostructures for harvesting visible-light energy [5,6]. In most of these methods, one material with a specific band gap is being produced.

The following equation describes the important role that hydrated electrons ($e_{aq}^-$) can play in the photodissociation of water:

$$e_{aq}^- + e_{aq}^- = H_2 + 2OH^- \quad (1)$$

This reaction proceeds with the reported rate constant of reaction 1, which is $k \approx 1 \times 10^{10} \text{ M}^{-1} \text{sec}^{-1}$ [18]. Under the photo excitation condition, [Fe(CN)$_6$]$^{3-}$ allows an electronic transition that produces hydrated electrons according to the following equation:

$$[\text{Fe(CN)}_6]^{3-} + h\nu = [\text{Fe(CN)}_6]^{4-} + e_{aq}^- \quad (2)$$

The disadvantage caused by the irreversibility of reaction 2 can be overcome through the use of a semiconductor system which acts as an electron donor and reduces [Fe(CN)$_6$]$^{3-}$ back to [Fe(CN)$_6$]$^{4-}$. The optimum conditions could be reached if the rate of reduction of [Fe(CN)$_6$]$^{3-}$ could be equated to the rate of formation of hydrated electrons from [Fe(CN)$_6$]$^{4-}$.

Heterogeneous reduction of hydrogen ions on colloidal suspensions of semiconductor’s nanoparticles is possible when a suitable hole-scavenger is present in the suspen-
sion medium. However, this process has several disadvantages: the limited conditions for such process to take place with respect to hydrogen ions; the great change in the pH at the surface of the semiconductor; and the effects on the semiconductor’s band gap position. With the high rate of photo-generation of hydrated electrons in homogenous solutions for reactions 1 and 2, it is possible that hydrogen can be generated heterogeneously and homogeneously by the photolysis of colloidal particles suspended in ferrocyanide solutions at room temperature.

Impurities in prepared metal oxides can affect their contribution to the photochemical behavior. Mixing some rare earth metal oxides with transition metal oxides may effectively reduce the impurities of the major component in the mixture [19]. This is because of the gettering effects of rare earth metals. Doping transition metal oxides with rare earth metal ions would guarantee the formation of a P-type semiconductor.

In this paper, we highlight the preparation of TiO2/Ce2O3 and TiO2/CeO2 and the effects of Ce(III) or Ce (IV) as f-elements dopant may cause on the semiconductor’s properties of TiO2 and on the rate of hydrogen production during the photolysis process using photons of visible light. The possibility of using these systems in a solar energy-based photolysis cell that achieve the goal of reversible, cyclic, and efficient process for hydrogen production is explored.

2. Experimental

2.1. Reagents

All the reagents were of analytical grade.

2.2. Preparation

Following the reported procedure [20], the following solutions were used: Solution A 2.843 g of Ti iso-propoxide/100 mL of CH2Cl2. Solution B 0.5486 g of (NH4)2CeNO3/10mL Di water; Solution C 5 g/100mL aqueous polyacrylamide solution (pH 12.7), Solution D: 0.40 g of Ce(NO3)3 in 6 mL of DI-water.

2.2.1. Synthesis of TiO2/CeO2 (4.5%)

Both solution A and B were added to solution C dropwise with constant stirring for 12 hours. The solid residue was separate using centrifuge. Dried at 70°C for 6 hours, followed by calcination for 6 hours at 600°C.

2.2.2. Synthesis of TiO2/Ce2O3 (9%)

Both solution A and D were added to solution C dropwise with constant stirring for 12 hours. The solid residue was separate using centrifuge. Dried at 70°C for 6 hours, followed by calcination for 6 hours at 600°C.

2.3. Instrumentation

2.3.1. Instrumentation

All electrochemical experiments were carried out using a conventional three electrode cell. A BAS 100 W electrochemical analyzer (Bioanalytical Co.) was used to perform the electrochemical studies. Steady reflectance spectra were performed using Shimadzu UV-2101 PC. Irradiations were performed with a solar simulator 300 watt xenon lamp (Newport) with an IR filter.

2.3.2. Photolysis Cell

Photolysis cell (Diagram 1), a one-compartment Pyrex cell with a quartz window facing the irradiation source [6]. The working electrode, a 10.0-cm² platinum gauze cylinder, had a solution volume of 100 mL. Suspensions of 20 mg of the studied nanomaterial/100 mL of aqueous phosphate buffer at pH 6 were stirred with a magnetic stirrer during the measurements. The pH was fixed at 6 because below this value formation of Fe6[Fe(CN)6]y was observed, while above pH 6 the photolysis of [Fe(CN)6]4⁻ was very slow. An Ag/AgCl/Cl⁻ reference electrode was also fitted into this compartment. A 10-cm² platinum counter electrode was housed in a glass cylinder sealed in one end with a fine porosity glass frit.

2.4. Preparation of Thin Solid Film Electrode

PolyVinyl Pyridine (PVP) Electrolyte: 0.02 g of PVP, 0.002 g of LiTFMS (Lithium tri-fluoromethanesulfonate), and 0.005 g of C12H24Br2 were all dissolved in 5 mL of DMF. 10 mg of SC powder was homogeneously dispersed in this solution and spread evenly on ITO (1.25 cm × 5 cm × 2 mm) and let dry at 60°C for 4 hours.

Photolysis using thin solid film: Diagram 2 illustrates the assembly of the thin solid-film electrode. The following is photoelectrochemical cell notation: ITO/Solid Electrolyte containing the SC/I2/I⁻ in Phosphate Buffer/Pt (Counter /AgAgCl (Ref).

3. Results and Discussion

3.1. Band-Energy Map of the Studied Oxides

The photo absorption behavior of the colloidal nanoparticles of the TiO$_2$/CeO$_2$ and TiO$_2$/Ce$_2$O$_3$ mixtures was investigated using steady state reflectance spectra. The results are displayed in Figures 1 and 2. The approximate values of the band gaps derived from these figures are listed in Table 1. The following equations [21] were used to determine whether direct or indirect transition band structures exist in these doped oxides:

\[
\left( \frac{\alpha E_g}{\epsilon} \right)^2 \propto E_g - E_d \quad (3)
\]

\[
\alpha \propto \left[ \left( E_g + E_p - E_y \right) / \left( E_g + E_p - E_y \right) \right]^2 + \left( E_g + E_p - E_y \right) / \left( E_g + E_p - E_y \right) \quad (4)
\]

where $\alpha$ is absorption coefficient, $E_g$ is the optical band gap.

The plot of $\alpha^{1/2}$ vs $E_g$ allows identification of indirect band transitions, while the plot of $(\alpha E_g)^2$ vs $E_g$ will allow the determination of the direct transitions. These plots are known as Tauc plots. The results of these treatments are displayed in Figures 1(b) and (c) for TiO$_2$/4.5% CeO$_2$ and in Figures 2(b) and (c) for TiO$_2$/9%Ce$_2$O$_3$ mixtures. The rest of the data listed in Table 1 are results of the analysis of Tauc plots.

The data listed in Table 1 indicate that addition of Ce(III) or Ce(IV) generally reduced the band gap of TiO$_2$. However, when the concentration of Ce(III) was twice that of Ce(IV) in the studied oxide mixtures resulted in small reduction of the doped TiO$_2$ band gap. Furthermore, the band gap of pure CeO$_2$ and that of Ce$_2$O$_3$ are of close values. Such behavior is expected because the 4f electron of Ce(III) is shielded by the outer filled shells of 5p and 5s electrons preventing the 4f electron from directly participating in bonding [22]. Similar discussion can be said about Ce(IV). The rare earth metal ions maintain much of the character exhibited by a free ion. The non-bonding property of the 4f dopant electrons is responsible for the well-known chemical similarity of different rare earth elements. The data listed in Table 1 also show that TiO$_2$ doped with either Ce(III) or Ce(IV) was less active in photo reduction of $[\text{Fe(CN)}_6]^{3-}$ than the pure oxides of TiO$_2$, Ce$_2$O$_3$, CeO$_2$, indicating that the change in the band gap resulted from shifting the conduction band position to a less positive potential vs NHE. It is well known that TiO$_2$ band positions shifts to more negative potential by increasing the pH [23]. At pH 6 our studies show that, the conduction band of pure TiO$_2$ shifts to $-0.1$ V vs NHE and the measured reduction potential of $[\text{Fe(CN)}_6]^{4-}$ at this pH is $0.40$ vs NHE. The approximate flat band

![Diagram 2. Thin solid film electrode assembly.](image)

![Figure 1. Diffusive reflectance spectrometry for TiO$_2$/CeO$_2$. (a) Absorption; (b) Indirect band gap; (c) Direct band gap.](image)

![Figure 2. Diffusive reflectance spectrometry for TiO$_2$/Ce$_2$O$_3$. (a) Absorption; (b) Indirect band gap; (c) Direct band gap.](image)

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potential measured for doped TiO₂ with Ce(III) and with Ce(IV) are 0.0 and −0.1 V vs NHE respectively (vida infra). This makes the approximate position of the conduction band at 0.1 and 0.0 V vs NHE for doped TiO₂ with Ce(III) and with Ce(IV) respectively. These data indicate that doping TiO₂ with Ce(III) or (IV) reduced its band gap by about 0.4 V. The small change in conduction band potential position in NHE scale suggests that doping caused a shift of valence band to a less positive potential.

3.2. Photolysis of Aqueous Doped Oxide Nano-Particles Colloidal Solutions

Photolysis of [Fe(CN)₆]⁴⁻ will generate hydrated electrons and [Fe(CN)₆]³⁻. The potential of the working electrode was fixed at 100 mV more negative than the reduction potential of [Fe(CN)₆]³⁻ to guarantee full reduction of ferricyanide. The current due to the reduction of [Fe(CN)₆]³⁻ collected by the working electrode during the photolysis process is a measure of photocurrent. The measured photocurrent was normalized assuming that two photons were absorbed for every one hydrogen molecule, and was used to calculate the number of moles of hydrogen generated per square meter per hour of illumination.

The contribution of the TiO₂ doped with cerium ions to the photochemical process in aqueous electrolytes can be tested by measuring the photo-reduction current and compare it with the total photoelectrochemical reduction current recorded during the photolysis process. Figure 3 displays the current-time curves recorded during the photolysis of 10 mM of [Fe(CN)₆]⁴⁻ in 0.2 M phosphate (pH 6) in the absence and presence of TiO₂ doped with Ce₂O₃. Figure 4 displays the current-time curves under similar conditions but in the presence of TiO₂ doped with CeO₂. Less current was generated in the presence of TiO₂ doped with either Ce₂O₃ or with CeO₂ than in the presence of pure metal oxides.

Understanding the results displayed in Figures 3 and 4 can be achieved using the model illustrated in Figure 5. Photolysis of [Fe(CN)₆]⁴⁻ according to Equation (2) in an oxide-free solution, results in formation of [Fe(CN)₆]³⁻. Electrochemical reduction of [Fe(CN)₆]³⁻ generates the peak (a), in Figure 5(A). In the presence of metal oxide mixtures, the recorded electrochemical reduction peak (b), is less in height than peak (a). This is attributed to the fact that, in the presence of semiconductor oxides, a portion of [Fe(CN)₆]⁴⁻ will be adsorbed on the surface of the oxide, which makes the recorded electrochemical reduction current of the working electrode less than in the absence of the oxide particles, so

\[ I_{\text{homogeneous}} > I_{\text{heterogeneous}} \]

where \( I_{\text{homogeneous}} = I \) (recorded in the absence of oxide particles) and \( I_{\text{heterogeneous}} = I \) (recorded in the presence of oxide particles)

\[ \text{The photochemical reduction due to oxides} = I_{\text{homogeneous}} - I_{\text{heterogeneous}} \]  

(5)

In a heterogeneous system (Diagram 3) the reduction of [Fe(CN)₆]³⁻ to [Fe(CN)₆]⁴⁻ takes place as follow:

\[ \text{H}_3\text{PO}_4 + \text{h} \text{ from (valence band)} = \text{H}_2\text{PO}_4^- \]  

(6)

The adsorbed [Fe(CN)₆]³⁻ on the particle captures electrons from CB (conduction band) according to this reaction:

\[ [\text{Fe(CN)}_6]^{3-} + (\text{e from CB}) = [\text{Fe(CN)}_6]^{4-} \]  

(7)

Completion of the reaction illustrated by Equation (7) guarantees continuation of reaction 2.

Figure 3. Photolysis of aqueous 10 mM [Fe(CN)₆]⁴⁻/phosphate buffer (pH = 6) in presence of TiO₂/Ce₂O₃ nanoparticles. (A) Ref no oxide added; (B) in presence of the oxide.

Figure 4. Photolysis of aqueous 10 mM [Fe(CN)₆]⁴⁻/phosphate buffer (pH = 6) in presence of TiO₂/CeO₂ nanoparticles.
of major active anions such as $\text{H}_2\text{PO}_4^-$ and $[\text{Fe(CN)}_6]^{3-}$ and retards the desired reaction represented by Equations (6) and (7). This negative effect on the photo activity can be explained assuming that CeO$_2$ adsorbed on the surface of TiO$_2$ created surface states where the recombination between electron/holes generated first by CeO$_2$ is possible. This will prevent injection of electrons into the CB of TiO$_2$, and prevent the holes of oxidizing $\text{H}_2\text{PO}_4^-$ (Diagram 3).

### 3.3. Thin Solid Films Behavior

Cyclic voltammograms (CVs) of TiO$_2$/Ce$_2$O$_3$, TiO$_2$/CeO$_2$ thin solid films loaded over FTO electrodes in the presence of $[\text{Fe(CN)}_6]^{4-}/^{3-}$ under illumination and under dark conditions are displayed in Figure 6. These CV’s indicate that the studied electrode assemblies are photoactive with the I$_2$/I$^-$ redox system. The observed photocurrent within the studied potential ranges indicates that $[\text{Fe(CN)}_6]^{4-}/^{3-}$ underwent electron accepting/donating processes. Such immobilization caused an adjustment of the flat band potential to accommodate these processes. These CVs also give an approximate value for the flat band potential, as at potential negative to $-0.3$ V and at $-0.2$ V (Figure 6(B)) a photocurrent is observed (Figure 6(A)). This is an indication of flat band potentials of TiO$_2$/Ce$_2$O$_3$ and TiO$_2$/CeO$_2$. Figure 7 displays linear sweep voltammetry (LSV) studies of TiO$_2$/CeO$_2$ thin solid films on FTO, in $[\text{Fe(CN)}_6]^{4-}/^{3-}$ and in I$^-$/I$_2$. It can be noticed that the recorded photocurrent in presence of I$^-$/I$_2$ (Figure 7(a2)) is greater than that recorded for $[\text{Fe(CN)}_6]^{4-}/^{3-}$ (Figure 7(b2)) at potentials that are more negative than the flat band.

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**Figure 5. Model for I-t for the photolysis of aqueous solution of $[\text{Fe(CN)}_6]^{3-}$. (A) In absence of nanoparticles; (B) In presence of nanoparticles.**

**Diagram 3. Energy map for TiO$_2$/CeO$_2$ assembly.**

Figure 3 shows that photolysis of homogenous solutions $[\text{Fe(CN)}_6]^{4-}$ reaches a peak current with a very short plateau, while the photolysis of a heterogeneous suspension of $[\text{Fe(CN)}_6]^{4-}$ (in presence of metal oxides) reaches a smaller peak height with a longer plateau. The longer plateau of electrochemical reduction current in the heterogeneous suspension than that in homogenous solutions can be attributed to the extra supply of $[\text{Fe(CN)}_6]^{3-}$ (as photo oxidation products) that is desorbed from the surfaces of the nanoparticles of the oxides and reached the Pt working electrode in later time. Sections (b) in Figure 5(A) and section (c) in Figure 5(B), represents electrochemical reduction current in darkness, hereafter described as “dark current”.

The data listed in Table 1 indicate that TiO$_2$ doped with either Ce$_2$O$_3$ or CeO$_2$ show the least photo activity toward reduction of $[\text{Fe(CN)}_6]^{3-}$ compared to that of pure oxides. Such behavior was previously reported for TiO$_2$ doped with increasing percentages of CeO$_2$ in presence of methylene blue (MB) where the activity if TiO$_2$ dropped when the percentage of Ce(IV) increased from 0.25% to more than 1% [20]. Assuming that the doped Ce oxides partially (adsorbed) covers the surface if TiO$_2$ when it is present at low concentrations (ca less than 1.0 %), the surface coverage becomes greater at higher percentages. Such adsorption competes with the adsorption of major active anions such as $\text{H}_2\text{PO}_4^-$ and $[\text{Fe(CN)}_6]^{3-}$ and retards the desired reaction represented by Equations (6) and (7). This negative effect on the photo activity can be explained assuming that CeO$_2$ adsorbed on the surface of TiO$_2$ created surface states where the recombination between electron/holes generated first by CeO$_2$ is possible. This will prevent injection of electrons into the CB of TiO$_2$, and prevent the holes of oxidizing $\text{H}_2\text{PO}_4^-$. (Diagram 3).

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**Figure 6. (A) CV of ITO/TeO$_2$/CeO$_2$ thin film in/ [Fe(CN)$_6$]$_{4-}^-$/Pt Cell a = CV under illumination; b = CV under dark; (B) CV of ITO/TeO$_2$/CeO$_2$ thin film in [Fe(CN)$_6$]$_{4-}^-$/Pt Cell a = Solid line = CV under illumination, b = dashed red line = CV under dark.**

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band potential.

Photolysis of an aqueous solution of 0.2 M phosphate containing 10 mM $I_2/I^-$ under a constant potential of $-0.800$ vs Ag/AgCl electrode using a thin solid films of TiO$_2$/CeO$_2$ on FTO as the photoactive electrode is displayed in Figure 8. The generated photocurrent is less than that recorded in aqueous suspensions (Figures 3 and 4). Such behavior is expected because the surface area of the photoactive material in the thin solid film is much less than that in the suspension system. Furthermore, the phenomena of dark current observed with thin films is much less than that observed with the suspensions, evidenced by the steeper drop in the photocurrent under dark. Figure 8 also shows reproducible photochemical activities through several cycles of darkness and illumination.

4. Conclusion

Doping TiO$_2$ with either Ce$_2$O$_3$ or CeO$_2$ alters the energy band structure of TiO$_2$. Ce(III/IV) addition reduced the band gap of doped TiO$_2$ resulting in shifting both conduction and valence band to more negative potential. The doped TiO$_2$ assemblies give less photochemical reduction of $[\text{Fe(CN)}_6]^{3-}$ than the oxides of pure metals (Ti or Ce). Such observed behavior was explained on the basis that the dopant facilitates the e/h recombination [20]. The possible existence of oxygen vacancies in presence of CeO$_2$ as a dopant enhances the chance of formation of localized states within the band gap range. These localized states lowered the rate of e/h recombination. This also explains why TiO$_2$/Ce$_2$O$_3$ gives less photoactivity than TiO$_2$/CeO$_2$ (Table 1).

REFERENCES


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